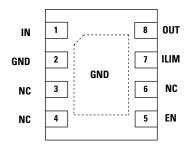
5 V, 5 A eFuse with Over Voltage and Over Current Protection





Pinout Designation



Top View

Pin Description

Pin#	Pin Name	Description
2	GND	Ground pin
1	IN	Input pin
8	OUT	Output pin. OUT is discharged to GND through an internal 80 Ω resistor during OVP event.
7	ILIM	Current limit program pin. Program the current limit by connecting a resister to ground. This pin can't be short to ground.
5	EN	Enable interface pin. Pull it above ON threshold to enable the IC. Pull it below OFF threshold to disable the IC.
3,4,6	NC	No Connection.

Description

The LS0505EVD22L integrated load switch provides a robust input over-current protection to downstream circuit systems. The device comes with built-in over-voltage protection, internal soft-start. The switch's low RDS(ON) minimizes power loss of the system. In the event of input over voltage, LS0505EVD22L immediately turns off the switch to prevent downstream system from stress of excessive high voltage. Set the current limit level with an external resistor. Internal soft-start ensures a smooth output voltage rampup and limits the input in-rush current.

Features & Benefits

- Wide Input Voltage Range from 2.7 V to 5.7 V
- 30 V Maximum Input / output Voltage
- Built-in Fast Response Over-Voltage Protection at 5.7 V
- 50 mΩ Low RDS(ON) Protection Switch
- Discharge Output at OVP

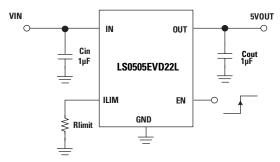
- Internal Soft-Start
- Thermal Shutdown
- Programmable Current Limit
 Peak Current up to 5 A
- Hiccup Mode Protection for Over Load or Short Circuit
- DFN2X2_8L Package
- Pb-Free and RoHS compliant

Applications

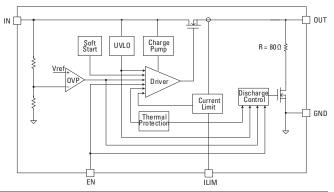
- Bluetooth Headsets
- Wearable Device
- Tablet PC

- Charging Cable
- Battery Devices
- Adapter Powered Devices

Typical Applications



Functional Block Diagram





5 V, 5 A eFuse with Over Voltage and Over Current Protection

Absolute Maximum Rating (Reference to GND)

Symbol	Value	Units
IN, OUT, EN	-0.3 to +30	V
ILIM	-0.3 to +6.5	V
ESD, Human Body Model (HBM)	±2000	V
Junction Temperature Range	-40 to +150	°C
Storage Temperature Range	-65 to +150	°C
Lead Temperature (Soldering 10s)	260	°C

Notes:

- 1. Stress exceeding those listed "Absolute Maximum Ratings" may damage the device.
- 2. ESD HBM testing per JESD22-A114F

Recommend Operating Conditions

Symbol	Value	Units
Input Voltage (IN)	+2.7 to +5.7	V
Junction Temperature Range	+125	°C

Notes: The device is not guaranteed to function outside of the recommended operating conditions.

Thermal information

Symbol	Value	Units
Maximum Power Dissipation ($T_A = 25$ °C)	1.52	W
Thermal Resistance (θ _{JA})	82	°C/W
Thermal Resistance ($\theta_{ m JC}$)	52	°C/W

Notes:

- 1. Measured on JESD51-7, 4-Layer PCB.
- **2.** The maximum allowable power dissipation is a function of the maximum junction temperature $T_{J,MMN'}$ the junction to ambient thermal resistance $\theta_{JN'}$ and the ambient temperature TA. The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_{O,MMN'} = T_{J,MMN'} T_{J,M} P_{J,M}$. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.

Electrical Characteristics ($T_A = +25$ °C, $V_{IN} = 5$ V, $C_{IN} = 1$ μ F, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V_{IN}	Input Voltage Range		2.7		5.7	V
 BIAS	Quiescent Current			200	260	μΑ
I _{SD}	Shutdown Current	$V_{EN} = 0V$		5	10	μΑ
R _{DS(ON)}	Power Switch On Resistance			50		mΩ
V_{UV}	Input Under-voltage Threshold			2.48		V
V_{UVHYS}	Input Under-voltage Hysteresis			180		mV
V_{ov}	Input Over-voltage Threshold			5.7		V
V_{ov}	Over Voltage Protection response time			250		ns
V_{ov}	Input Over-voltage Hysteresis			330		mV
T_{ss}	Soft-start Slew Rate Time			230		μs
1	Current Limit	R_{LIM} =500 k Ω	1.35	1.5	1.65	А
LIMT	Current Limit	I _{LIM} pin float		5		A
K _{LIM}	Current Limit Setting Factor	I _{INLIM} =1 A~5 A	675	750	825	A*kΩ
R_{Disch}	OUT Discharging Resistance	V _{IN} =6.5 V		80		Ω
V_{IH_EN}	EN Logic High Input Voltage		1.2			V
V_{IL_EN}	EN Logic Low Input Voltage				0.4	V
T _{SD}	Thermal Shutdown Temperature			160		°C
T_{HYS}	Thermal Shutdown Hysteresis			40		°C



5 V, 5 A eFuse with Over Voltage and Over Current Protection

Figure 1 - Quiescent Current vs. Input Voltage

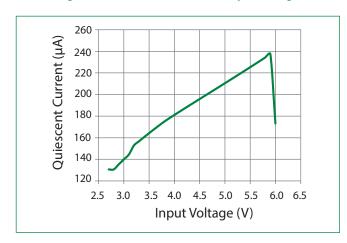


Figure 3 - V_{IN} On (5 V_{IN} , I_{O} = 0 A)

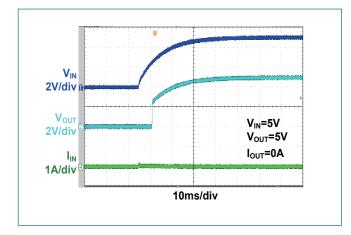


Figure 5 - V_{IN} On (5 V_{IN} , I_{O} = 3 A)

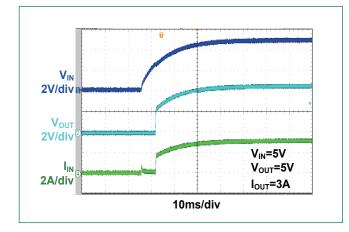


Figure 2 - RLimit vs. Ilimit (5V_{IN} Application)

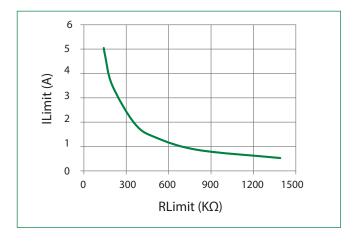


Figure 4 - Vin Off (5 V_{IN} , I_{O} = 0 A)

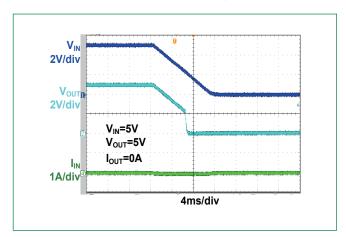
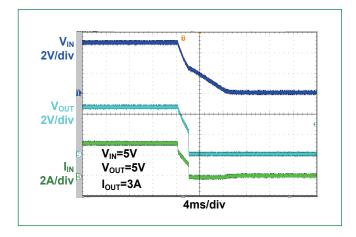


Figure 6 - V_{IN} Off (5 V_{IN} , I_{O} = 3 A)





5 V, 5 A eFuse with Over Voltage and Over Current Protection

Figure 7 - Soft Start (3.3 V_{IN} , $I_O = 0$ A)

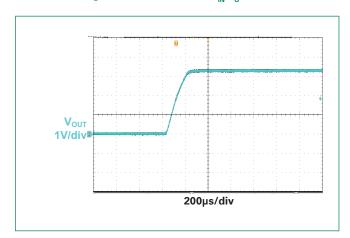


Figure 9 - Current Limit ($5V_{IN}$, Rlimit = float)

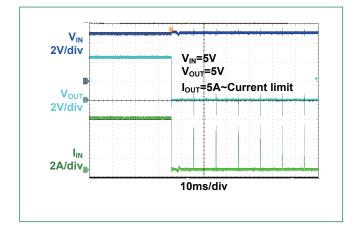


Figure 11 - Short Protection ($5V_{IN}$, Rlimit = float)

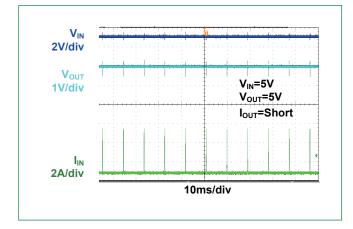


Figure 8 - Soft Start (5 V_{IN} , $I_{O} = 0$ A)

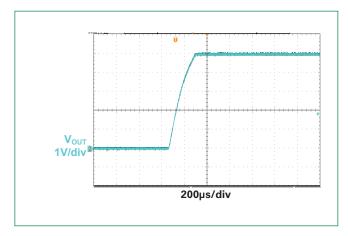


Figure 10 - Current Limit ($5V_{IN}$, Rlimit = 500 k)

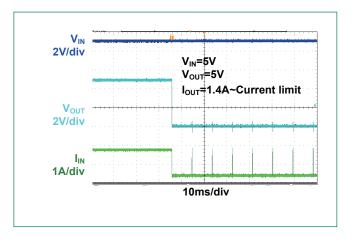
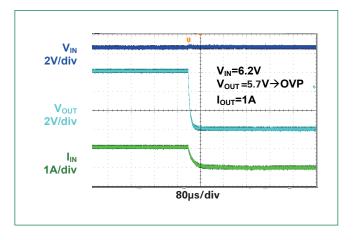


Figure 12 - Over Voltage Protection ($5V_{IN}$ Application, $I_{O} = 1$ A)





5 V, 5 A eFuse with Over Voltage and Over Current Protection

Detailed Description

The LS0505EVD22L is a fully integrated load switch with built-in over-voltage protection, internal soft-start and programmable current limit. When the input voltage is within the valid range(2.7 V~5.7 V), the output pin OUT will ramp up with a fixed slew rate defined by internal soft-start. After OUT ramps up to input level, the internal load switch is fully turned on and ready to supply power to the system. LS0505EVD22L continuously monitors the system load current through the switch when the power is on. Once the load current reaches

the current limit ILIMT programmed by ILIMT pin, LS0505EVD22L will regulate the load current for 60 µs to prevent the load current from running away. After 60 µs, if the current limit condition sustains, LS0505EVD22L will turn off the load switch, wait for 8 ms and then try to re-start. In the event of system short circuit failure, the load current could jump significantly higher than the current limit. Whenever the load current is 2 A larger than the current limit level, LS0505EVD22L immediately turns off the load switch to prevent device damage and waits for 8ms before it tries to re-start.

LS0505EVD22L has an internal input OVP to protect the system from being stressed by excessively high voltage. Once it detects input voltage is higher than the built-in over-voltage threshold, LS0505EVD22L immediately turns off the load switch. The load switch turns on automatically once the input voltage falls within the valid range.

The LS0505EVD22L also has thermal shutdown protection, when device temperature (T_J) exceeds $T_{SHDN'}$ typically 160 °C, the thermal shutdown circuitry will shut down the internal MOSFET thereby disconnecting the load from the input supply. The LS0505EVD22L will remain off until the device temperature falls below T_{SHDN} -40 °C, after which it will attempt to restart.

Programmable Over-Current Protection

A programmable current limit level and short circuit current protection has been designed to prevent the load current overload the regulator. When the input current limit loop is engaged, input current will be automatically reduced to the pre-determined level which is set by I_{LIM} pin, and regulate the load current for 60 μ s, then enter hiccup mode waiting for 8 ms to reduce power dissipation. When a short event happens, the short protection circuit will be triggered and turn off power switch quickly, LS0505EVD22L will restart after 8 ms. The output can be shorted to ground indefinitely without damaging the part.

Input current limit can be programmed with below equation:

$$I_{INLIM} = \frac{750A * k\Omega}{R_{ILIM}}$$

Where R_{IIM} is the program resistor at the I_{LIM} pin.

Program Current Limit Resistance (kΩ)	750	375	250	187.5	150
Current Limit I (A)	1	2	3	4	5

For the stable system operation, recommend to set the current limit level 1.2~1.5 times of the maximum system load current to avoid mis-triggering the current limit and causing system malfunctions.

Soft Start

When LS0505EVD22L is power on, VOUT will ramp up with a controlled rising time for minimizing inrush current.

Enable

Enable interface pin. Pull it above ON threshold High to enable the IC. Pull it below OFF threshold to disable the IC.

Input and Output Capacitor Selection

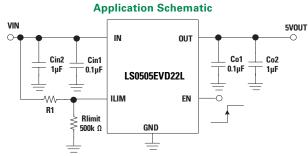
The LS0505EVD22L require ≥1 µF input and output capacitor connected to GND. Although X7R type capacitors are recommended, X5R and others may be used.

PCB Layout Guideline

- For all applications, a 0.1 μF or greater ceramic decoupling capacitor is recommended between IN terminal and GND, and a 0.1 μF or greater ceramic decoupling capacitor is recommended between OUT terminal and GDN. For hot-plug applications, where input power path inductance is negligible, this capacitor can be eliminated/minimized.
- The optimum placement of decoupling capacitor is closest to the IN and GND terminals of the device. Care must be taken to minimize the loop area formed by the bypass-capacitor connection, the IN terminal, and the GND terminal of the IC.
- High current carrying power path connections should be as short as possible and should be sized to carry at least twice the full-load current.
- The GND terminal must be tied to the PCB ground plane at the terminal of the IC. The PCB ground should be a copper plane or island on the board
- Obtaining acceptable performance with alternate layout schemes is possible; however, this layout has been shown to produce good results and is intended as a guideline.



5 V, 5 A eFuse with Over Voltage and Over Current Protection



Bill of Materials

Qty	Ref	Value	Description	Package
2	CIN2, CO2	1 μF	Ceramic Capacitor, 35 V, X5R	0805
2	CIN1, CO1	0.1 μF	Ceramic Capacitor, 35 V, X5R	0603
1	Rlimit	500 kΩ	Resistor, ±1 %	0603
1	R1	NC	Resistor, ±1 %	0603
1	U1	LS0505EVD22L	eFuse IC	DFN2x2_8L

Soldering Parameters

Average Ramp	Up Rate (Tsmin toT _p)	1~2 °C/second, 3 °C/second max
	-Temperature Min (T _{s(min)})	150 °C
Preheat & Soak	-Temperature Max (T _{s(max)})	200 °C
Joun	-Time (min to max) (t _s)	60 - 120 secs
Time	- Temperature(T _L)	217 °C
Maintained Above	-Time(t _L)	60~150 seconds
Peak Temperat	cure (T _P)	See Classification Temp in table1
Time Within 5	30 seconds max	
Ramp-down R	ate	6 °C/second max
Time 25 °C to	Peak Temperature (T₀)	8 minutes max

Notes:

- 1. Tolerance for peak profile Temperature(Tp) is defined as a supplier minimum and a user maximum.
- 2. Tolerance for time at peak profile temperature (tp)is defined as a supplier minimum and a user maximum.

Ordering Information

Part Number	Package	Min Order Qty
LS0505EVD22L	DFN2x2_8L	3000/Tape & Reel

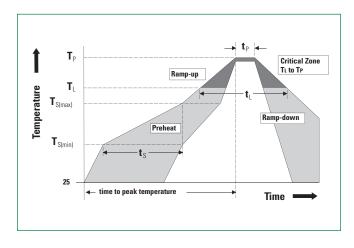


Table 1: Pb-free Process -Classification Temperatures (T_c)

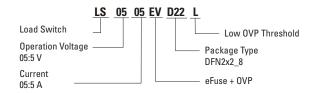
Package Thickness	Volume mm³ <350	Volume mm³ 350-2000	Volume mm³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm-2.5 mm	260 °C	250 °C	245 °C
>2.5 mm	250 °C	245 °C	245 °C
-	3,4,5,6	NC	No Connection

Note: For all temperature information, please refer to topside of the package, measured on the package body surface.

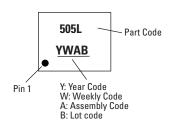


5 V, 5 A eFuse with Over Voltage and Over Current Protection

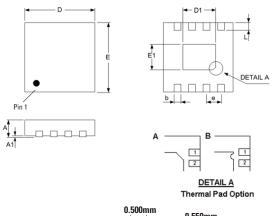
Part Numbering



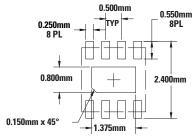
Part Marking



Dimensions - DFN2x2_8L

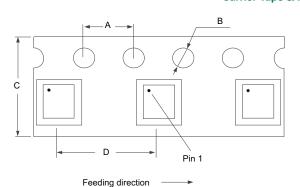


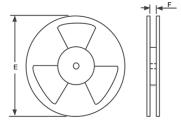
Dii	Millin	Millimeters		hes
Dimension	Min	Max	Min	Max
А	0.70	0.80	0.028	0.031
A1	0.00	0.05	0.000	0.002
b	0.18	0.30	0.007	0.012
D	1.90	2.10	0.075	0.083
D1	1.10	1.70	0.043	0.067
Е	1.90	2.10	0.075	0.083
E1	0.50	0.70	0.020	0.028
е	0.50		0.0)20
L	0.20	0.40	0.008	0.016



Recommended Soldering Pad Layout

Carrier Tape & Reel Specification — DFN2x2_8L





Symbol	Millimeters
Α	4.0
В	1.5
С	8.0
D	4.0
E	7 inch
F	9.0

